

### **Optocoupler with Phototransistor Output**

#### **Description**

The CNY21Exi consists of a phototransistor optically coupled to a gallium arsenide infrared-emitting diode in a 4-lead plastic dual inline package.

The single components are mounted on one leadframe in opposite oneanother, providing a fixed distance between input and output for highest safety requirements of > 3 mm.



### **Applications**

Used for circuits with intrinsic safety Ex-i (G5).

PTB-approval-file number Ex-90.C.2106 U confirms that this coupler can be used for intrinsic circuits up to a line in the voltage range  $\leq 375$  V.

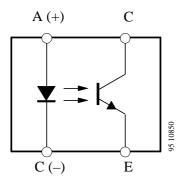


#### **Features**

- UL-recognized file No: E 76414
- DC isolation test voltage: 10 kV
- Creepage current resistance of isolation material according to VDE 0303/DIN 53480: KB ≥ 150/KC ≥ 175
- Isolation material according to UL 94 flammability class

- Test class 25/100/21 DIN 40045
- Very low coupling capacity of typical 0.3 pF, therefore high noise voltage resistant
- Current Transfer Ratio (CTR) of typical 80%
- Low temperature coefficient of CTR

#### **Pin Connection**



# CNY21Exi



### **Absolute Maximum Ratings**

### **Input (Emitter)**

| Parameters            | Test Conditions           | Symbol           | Value | Unit |
|-----------------------|---------------------------|------------------|-------|------|
| Reverse voltage       |                           | $V_R$            | 5     | V    |
| Forward current       |                           | I <sub>F</sub>   | 50    | mA   |
| Forward surge current | $t_p \le 1 \mu s$         | I <sub>FSM</sub> | 1.5   | A    |
| Power dissipation     | $T_{amb} \le 25^{\circ}C$ | P <sub>V</sub>   | 120   | mW   |
| Junction temperature  |                           | Ti               | 100   | °C   |

### **Output (Detector)**

| Parameters                | Test Conditions                      | Symbol           | Value | Unit |
|---------------------------|--------------------------------------|------------------|-------|------|
| Collector emitter voltage |                                      | V <sub>CEO</sub> | 32    | V    |
| Emitter collector voltage |                                      | V <sub>ECO</sub> | 5     | V    |
| Collector current         |                                      | $I_{C}$          | 50    | mA   |
| Collector peak current    | $t_p/T = 0.5, t_p \le 10 \text{ ms}$ | I <sub>CM</sub>  | 100   | mA   |
| Power dissipation         | $T_{amb} \le 25^{\circ}C$            | P <sub>V</sub>   | 130   | mW   |
| Junction temperature      |                                      | T <sub>i</sub>   | 100   | °C   |

### Coupler

| Parameters                | Test Conditions                      | Symbol             | Value                | Unit |
|---------------------------|--------------------------------------|--------------------|----------------------|------|
| DC isolation test voltage | t = 1 min                            | V <sub>IO</sub> 1) | 10                   | kV   |
| Total power dissipation   | $T_{amb} \le 25^{\circ}C$            | P <sub>tot</sub>   | P <sub>tot</sub> 250 |      |
| Ambient temperature range |                                      | T <sub>amb</sub>   | -55 to +85           | °C   |
| Storage temperature range |                                      | T <sub>stg</sub>   | −55 to +100          | °C   |
| Soldering temperature     | 2 mm from case, $t \le 10 \text{ s}$ | T <sub>sd</sub>    | 260                  | °C   |

<sup>1)</sup> Related to standard climate 23/50 DIN 50014



#### **Electrical Characteristics**

 $T_{amb} = 25^{\circ}C$ 

### **Input (Emitter)**

| Parameters           | Test Conditions         | Symbol           | Min. | Тур. | Max. | Unit |
|----------------------|-------------------------|------------------|------|------|------|------|
| Forward voltage      | $I_F = 50 \text{ mA}$   | $V_{\mathrm{F}}$ |      | 1.25 | 1.6  | V    |
| Breakdown voltage    | $I_R = 100 \mu A$       | $V_{(BR)}$       | 5    |      |      | V    |
| Junction capacitance | $V_R = 0$ , $f = 1$ MHz | C <sub>i</sub>   |      | 50   |      | pF   |

### **Output (Detector)**

| Parameters                          | Test Conditions   | Symbol               | Min. | Тур. | Max. | Unit |
|-------------------------------------|---|----------------------|------|------|------|------|
| Collector emitter breakdown voltage | $I_C = 1 \text{ mA}$  | V <sub>(BR)CE0</sub> | 32   |      |      | V    |
| Emitter collector breakdown voltage | $I_E = 100 \mu A$   | V <sub>(BR)EC0</sub> | 5    |      |      | V    |
| Collector dark current              | $\begin{aligned} V_{CE} &= 20 \text{ V, } I_f = 0, \\ E &= 0 \end{aligned}$ | I <sub>CE0</sub>     |      |      | 200  | nA   |

### Coupler

| Parameters                           | Test Conditions   | Symbol             | Min. | Тур.             | Max. | Unit |
|--------------------------------------|---|--------------------|------|------------------|------|------|
| DC isolation test voltage            | t = 1 min   | V <sub>IO</sub>    | 10   |                  |      | kV   |
| Isolation resistance                 | $V_{IO} = 1000 \text{ V},$ $40\%$ relative humidity               | R <sub>IO</sub>    |      | 10 <sup>14</sup> |      | Ω    |
| $I_{C}/I_{F}$                        | $I_F = 10 \text{ mA}, V_{CE} = 5 \text{ V}$                       | CTR                | 0.5  | 0.8              |      |      |
| Collector emitter saturation voltage | $I_F = 10 \text{ mA}, I_C = 1 \text{ mA}$                         | V <sub>CEsat</sub> |      |                  | 0.3  | V    |
| Cut-off frequency                    | $V_{CE} = 5 \text{ V}, I_F = 5 \text{ mA},$<br>$R_L = 100 \Omega$ | $f_c$              |      | 170              |      | kHz  |
| Coupling capacitance                 | f = 1 MHz   | $C_k$              |      | 0.3              |      | pF   |



### **Switching Characteristics**

 $V_S = 5 V$ 

| Toma     |                     |                     | $R_{L} = 10$ | $0 \Omega$ (see     | figure 1            | )                     |                     | $R_L = 1 \text{ k}\Omega$ (see figure 2) |                       |                     |  |
|----------|---------------------|---------------------|--------------|---------------------|---------------------|-----------------------|---------------------|--|-----------------------|---------------------|--|
| Туре     | t <sub>d</sub> [µs] | t <sub>r</sub> [µs] | ton[µs]      | t <sub>s</sub> [µs] | t <sub>f</sub> [µs] | t <sub>off</sub> [µs] | I <sub>C</sub> [mA] | ton[µs]                                  | t <sub>off</sub> [µs] | I <sub>F</sub> [mA] |  |
| CNY21Exi | 2.6                 | 2.4                 | 5.0          | 0.3                 | 2.7                 | 3.0                   | 5                   | 11                                       | 13.5                  | 20                  |  |

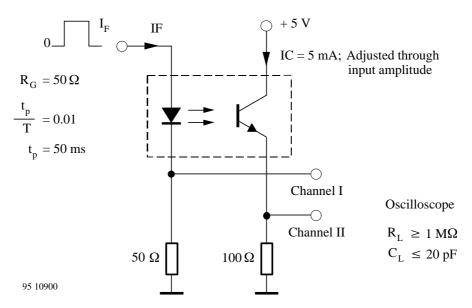


Figure 1. Test circuit, non-saturated operation

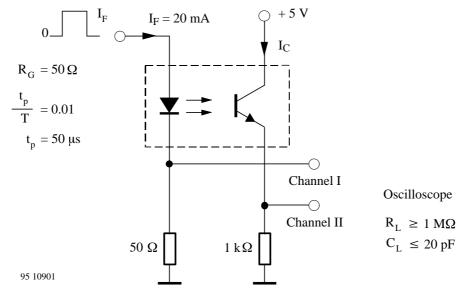


Figure 2. Test circuit, saturated operation

#### **Typical Characteristics** ( $T_{amb} = 25$ °C, unless otherwise specified)

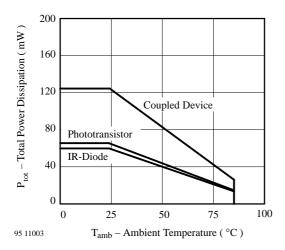


Figure 3. Total Power Dissipation vs. Ambient Temperature

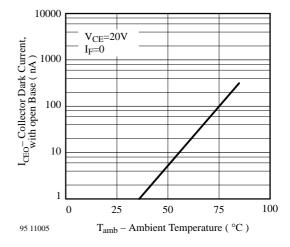


Figure 6. Collector Dark Current vs. Ambient Temperature

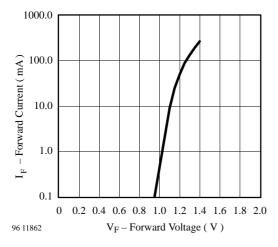


Figure 4. Forward Current vs. Forward Voltage

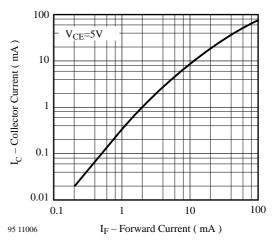


Figure 7. Collector Current vs. Forward Current

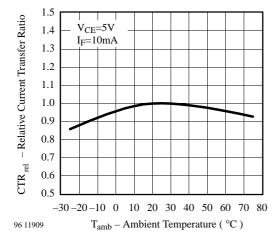


Figure 5. Rel. Current Transfer Ratio vs. Ambient Temperature

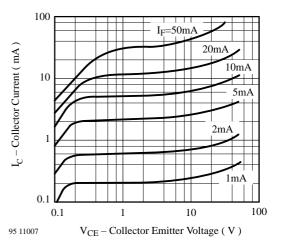


Figure 8. Collector Current vs. Collector Emitter Voltage



## **Typical Characteristics** ( $T_{amb} = 25$ °C, unless otherwise specified)

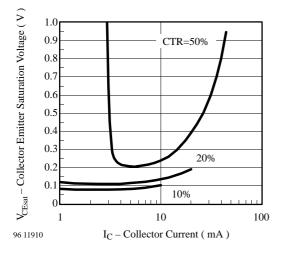


Figure 9. Collector Emitter Sat. Voltage vs. Collector Current

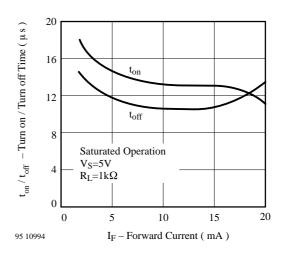


Figure 11. Turn on / off Time vs. Forward Current

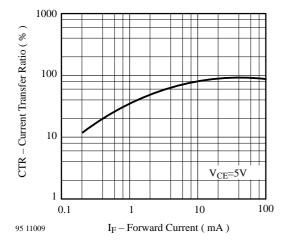


Figure 10. Current Transfer Ratio vs. Forward Current

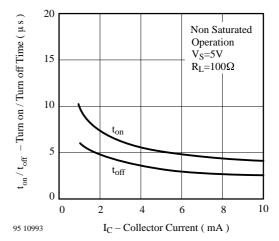
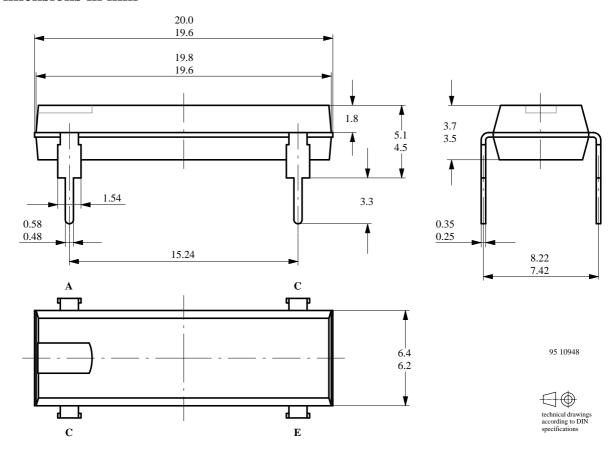


Figure 12. Turn on / off Time vs. Collector Current



### **Dimensions in mm**



## CNY21Exi



#### **Ozone Depleting Substances Policy Statement**

It is the policy of TEMIC TELEFUNKEN microelectronic GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

**TEMIC TELEFUNKEN microelectronic GmbH** semiconductor division has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

**TEMIC** can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use TEMIC products for any unintended or unauthorized application, the buyer shall indemnify TEMIC against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

TEMIC TELEFUNKEN microelectronic GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany Telephone: 49 (0)7131 67 2831, Fax number: 49 (0)7131 67 2423